

Test Report

頁數(Page): 1 of 10 號碼(No.): CE/2018/25844 日期(Date): 2018/03/06

詮璨科技股份有限公司 SEMTRON MICROTECH CORPORATION 新北市中和區建康路158號4樓 4F, NO. 158, JIANKANG RD., JHONGHE DISTRICT, NEW TAIPEI CITY 23586. TAIWAN

以下測試樣品係由申請廠商所提供及確認 (The following sample(s) was/were submitted and identified by/on behalf of the applicant as):

送樣廠商(Sample Submitted By) 詮璨科技股份有限公司 (SEMTRON MICROTECH CORPORATION)

樣品名稱(Sample Description) IC, DISCRETES

T0-220, T0-220F, T0-247, T0-251, T0-252, T0-263-5L, S0P-8, 樣品型號(Style/Item No.)

> ESOP-8, TSSOP-8, SOD-523, SOT-23, SOT-23L, SOT-23-5L, SOT-23-6L, SOT-363, TSOT-23-6LSOT-89, SOT-89-5L, SOT-223, DFN2X2-6B, DFN2X2-6C, DFN2X2-6G, DFN2X2-8B, DFN2X3-6,

DFN2X3-8, DFN3X3-8, DFN3X3-10, DFN3X3-16,

DFN3. 3X3. 3-8_EP, DFN5X6, DFN5X6-8

收件日期(Sample Receiving Date) 2018/02/26

測試期間(Testing Period) 2018/02/26 TO 2018/03/06

測試結果(Test Results) : 請參閱下一頁 (Please refer to following pages).





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測試結果(Test Results)

測試部位(PART NAME)No.1 : 整體混測 (MIXED ALL PARTS)

測試項目 (Test Items)	單位 (Unit)	測試方法 (Method)	方法偵測 極限值 (MDL)	結果 (Result) No.1
鎬 / Cadmium (Cd)	mg/kg	参考IEC 62321-5 (2013),以感應耦合 電漿原子發射光譜儀檢測. / With reference to IEC 62321-5 (2013) and performed by ICP-AES.	2	n. d.
鉛 / Lead (Pb)	mg/kg	参考IEC 62321-5 (2013),以感應耦合 電漿原子發射光譜儀檢測. / With reference to IEC 62321-5 (2013) and performed by ICP-AES.	2	52. 6
汞 / Mercury (Hg)	mg/kg	参考IEC 62321-4 (2013),以感應耦合 電漿原子發射光譜儀檢測. / With reference to IEC 62321-4 (2013) and performed by ICP-AES.	2	n. d.
六價鉻 / Hexavalent Chromium Cr(VI) (◆)	mg/kg	參考IEC 62321-7-2 (2017),以UV-VIS 檢測;參考IEC 62321-5 (2013),以 ICP-AES檢測. / With reference to IEC 62321-7-2 (2017) and performed by UV-VIS.; With reference to IEC 62321-5 (2013) and performed by ICP-AES.	8	n. d.



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測試項目 (Test Items)	單位 (Unit)	測試方法 (Method)	方法偵測 極限值	結果 (Result)
(Test Tiems)	(UIII t)	(Method)	(MDL)	No. 1
多溴聯苯總和 / Sum of PBBs	mg/kg		-	n. d.
一溴聯苯 / Monobromobiphenyl	mg/kg		5	n. d.
二溴聯苯 / Dibromobiphenyl	mg/kg		5	n. d.
三溴聯苯 / Tribromobiphenyl	mg/kg		5	n. d.
四溴聯苯 / Tetrabromobiphenyl	mg/kg		5	n. d.
五溴聯苯 / Pentabromobiphenyl	mg/kg		5	n. d.
六溴聯苯 / Hexabromobiphenyl	mg/kg		5	n. d.
七溴聯苯 / Heptabromobiphenyl	mg/kg		5	n. d.
へ溴聯苯 / Octabromobiphenyl	mg/kg		5	n. d.
九溴聯苯 / Nonabromobiphenyl	mg/kg	多考IEC 62321-6 (2015),以氣相層析	5	n. d.
十溴聯苯 / Decabromobiphenyl	mg/kg	/質譜儀檢測. / With reference to	5	n. d.
多溴聯苯醚總和 / Sum of PBDEs	mg/kg	IEC 62321-6 (2015) and performed	-	n. d.
一溴聯苯醚 / Monobromodiphenyl ether	mg/kg	by GC/MS.	5	n. d.
二溴聯苯醚 / Dibromodiphenyl ether	mg/kg		5	n. d.
三溴聯苯醚 / Tribromodiphenyl ether	mg/kg		5	n. d.
四溴聯苯醚 / Tetrabromodiphenyl ether	mg/kg		5	n. d.
五溴聯苯醚 / Pentabromodiphenyl ether	mg/kg		5	n. d.
六溴聯苯醚 / Hexabromodiphenyl ether	mg/kg]	5	n. d.
七溴聯苯醚 / Heptabromodiphenyl ether	mg/kg]	5	n. d.
八溴聯苯醚 / Octabromodiphenyl ether	mg/kg]	5	n. d.
九溴聯苯醚 / Nonabromodiphenyl ether	mg/kg]	5	n. d.
十溴聯苯醚 / Decabromodiphenyl ether	mg/kg		5	n. d.



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測試項目 (Test Items)	單位 (Unit)	測試方法 (Method)	方法偵測 極限値 (MDL)	結果 (Result) No.1
鄰苯二甲酸丁苯甲酯 / BBP (Butyl Benzyl phthalate) (CAS No.: 85-68-7)	mg/kg	參考IEC 62321-8 (2017),以氣相層析儀/質譜儀檢測./With reference to IEC 62321-8 (2017). Analysis was performed by GC/MS.	50	n. d.
鄰苯二甲酸二丁酯 / DBP (Dibutyl phthalate) (CAS No.: 84-74-2)	mg/kg		50	n. d.
鄰苯二甲酸二異丁酯 / DIBP (Di-isobutyl phthalate) (CAS No.: 84-69-5)	mg/kg		50	n. d.
鄰苯二甲酸二 (2-乙基己基)酯 / DEHP (Di- (2-ethylhexyl) phthalate) (CAS No.: 117-81-7)	mg/kg		50	n. d.
鄰苯二甲酸二異癸酯 / DIDP (Di- isodecyl phthalate) (CAS No.: 26761- 40-0; 68515-49-1)	mg/kg		50	n. d.
鄰苯二甲酸二異壬酯 / DINP (Di-isononyl phthalate) (CAS No.: 28553-12-0; 68515-48-0)	mg/kg		50	n. d.
鄰苯二甲酸二正辛酯 / DNOP (Di-n-octyl phthalate) (CAS No.: 117-84-0)	mg/kg		50	n. d.
鹵素 / Halogen				
鹵素(氟)/ Halogen-Fluorine (F) (CAS No.: 14762-94-8)	mg/kg	参考BS EN 14582 (2016),以離子層析 儀分析. / With reference to BS EN 14582 (2016). Analysis was performed by IC.	50	n. d.
鹵素 (氣) / Halogen-Chlorine (C1) (CAS No.: 22537-15-1)	mg/kg		50	n. d.
鹵素(溴)/ Halogen-Bromine (Br) (CAS No.: 10097-32-2)	mg/kg		50	n. d.
鹵素(碘)/ Halogen-Iodine(I)(CAS No.: 14362-44-8)	mg/kg		50	n. d.



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備註(Note):

- 1. mg/kg = ppm ; 0.1wt% = 1000ppm
- 2. n.d. = Not Detected (未檢出)
- 3. MDL = Method Detection Limit (方法偵測極限值)
- 4. "-" = Not Regulated (無規格值)
- 5. **(\ldot)**:

若鉻含量小於六價鉻之方法偵測極限值,則六價鉻為n.d.,不須再測試六價鉻。

The result of Cr(VI) is "n.d." as the result of Chromium (Cr) is less than the MDL of Cr(VI), and confirmation test of Cr(VI) is not required.

若鉻含量未小於六價鉻之方法偵測極限值,需進行六價鉻測試。

If the Chromium (Cr) content is not less than the MDL of Cr(VI), confirmation test of Cr(VI) is required.

6. 樣品的測試是基於申請人要求混合測試,報告中的混合測試結果不代表其中個別單一材質的含量. (The samples was/were analyzed on behalf of the applicant as mixing sample in one testing. The above results was/were only given as the informality value.)

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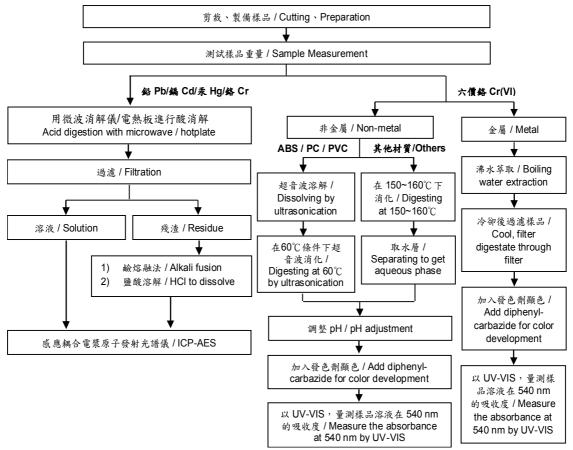
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重金屬流程圖 / Analytical flow chart of Heavy Metal

根據以下的流程圖之條件,樣品已完全溶解。(六價鉻測試方法除外)

These samples were dissolved totally by pre-conditioning method according to below flow chart. (Cr^{6+} test method excluded)

- 測試人員:王志瑋 / Technician: JR Wang
- 測試負責人:張啟興 / Supervisor: Troy Chang





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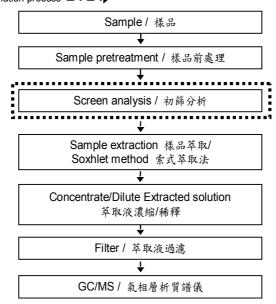
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多溴聯苯/多溴聯苯醚分析流程圖 / Analytical flow chart - PBB/PBDE

測試人員:涂雅苓 / Technician: Yaling Tu

測試負責人:張啟興 / Supervisor: Troy Chang

初次測試程序 / First testing process _ 選擇性篩檢程序 / Optional screen process ******* 確認程序 / Confirmation process - - - →





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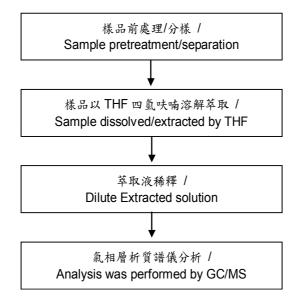
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<u>可塑劑分析流程圖 / Analytical flow chart - Phthalate</u>

測試人員:徐毓明 / Technician: Andy Hsu

測試負責人:張啟興 / Supervisor: Troy Chang

【測試方法/Test method: IEC 62321-8】





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<u> 鹵素分析流程圖 / Analytical flow chart - Ha</u>logen

測試人員:陳恩臻 / Technician: Rita Chen 測試負責人:張啟興 / Supervisor: Troy Chang

樣品前處理/分樣 / Sample pretreatment/separation 秤重及將樣品放入樣品槽中/ Weighting and putting sample in cell 燃燒彈/吸收 Oxygen Bomb Combustion / Absorption 稀釋至固定體積 / Dilution to fixed volume 離子層析儀分析 / Analysis was performed by IC



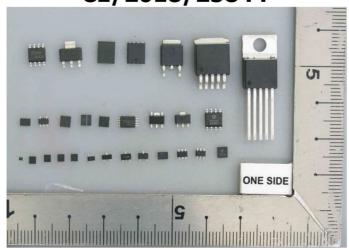
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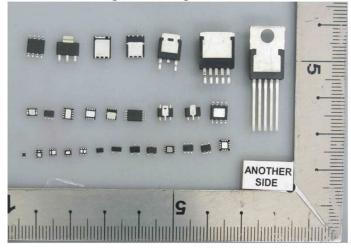
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> * 照片中如有箭頭標示,則表示為實際檢測之樣品/部位. * (The tested sample / part is marked by an arrow if it's shown on the photo.)

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** 報告結尾 (End of Report) **